

Tailoring molecular termination for thermally stable perovskite solar cells

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Abstract: Interfacial engineering has made an outstanding contribution to the development of high-efficiency perovskite solar cells (PSCs). Here, we introduce an effective interface passivation strategy via methoxysilane molecules with different terminal groups. The power conversion efficiency (PCE) has increased from 20.97% to 21.87% after introducing a 3-isocyanatopropyltrimethoxy silane (IPTMS) molecule with carbonyl group, while a trimethoxy[3-(phenylamino)propyl] silane (PAPMS) molecule containing aniline group deteriorates the photovoltaic performance as a consequence of decreased open circuit voltage. The improved performance after IPTMS treatment is ascribed to the suppression of non-radiative recombination and enhancement of carrier transportation. In addition, the devices with carbonyl group modification exhibit outstanding thermal stability, which maintain 90% of its initial PCE after 1500 h exposure. This work provides a guideline for the design of passivation molecules aiming to deliver the efficiency and thermal stability simultaneously.

Key words: perovskite solar cells; terminal groups; interfacial engineering; thermal stability

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Supplement Materials

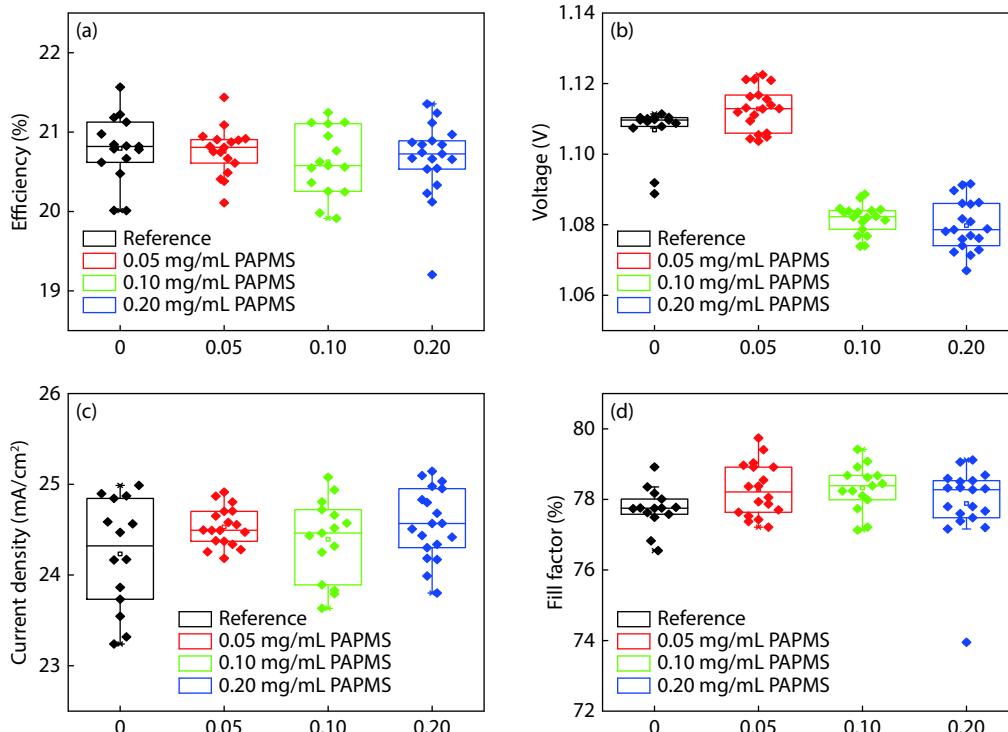


Fig. S1. Statistics of the device performance parameters for solar cells fabricated with different concentrations of PAPMS. (a) PCE. (b) V_{oc} . (c) J_{sc} . (d) FF.

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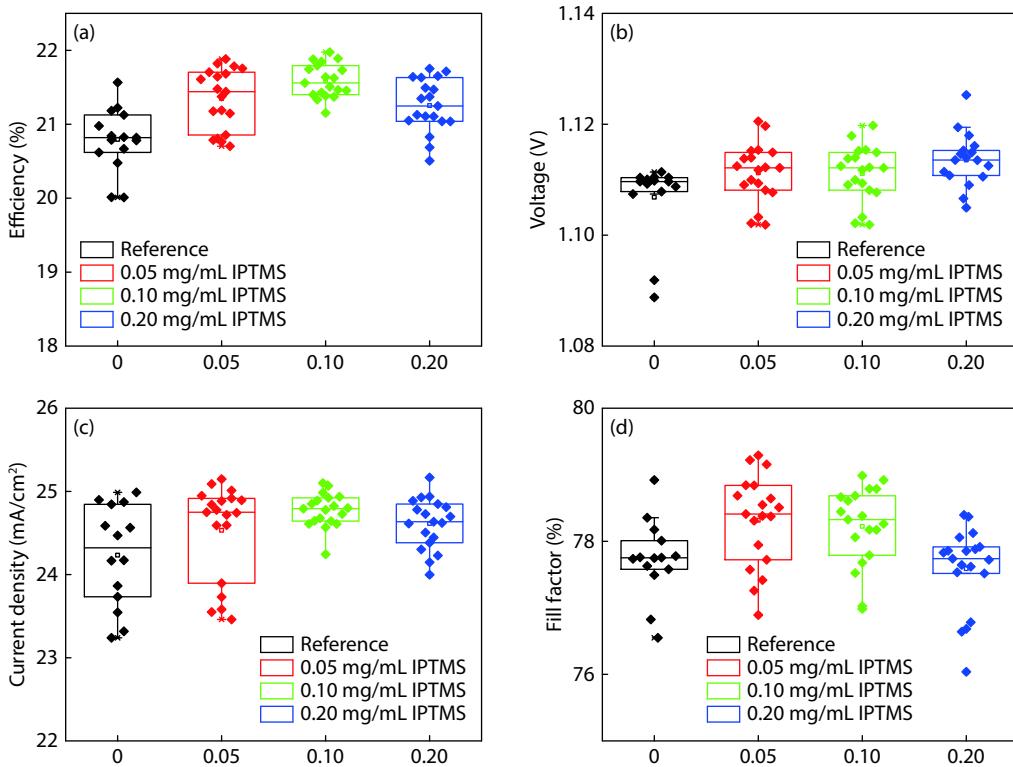


Fig. S2. Statistics of the device performance parameters for solar cells fabricated with different concentrations of IPTMS. (a) PCE. (b) V_{oc} . (c) J_{sc} . (d) FF.

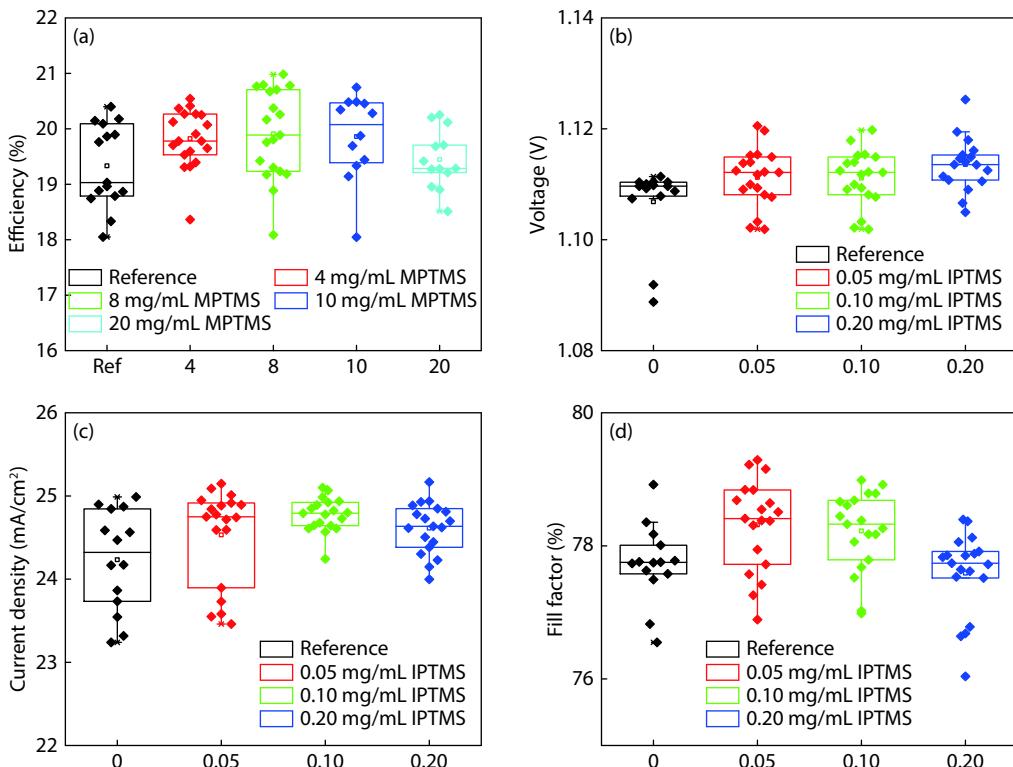


Fig. S3. Statistics of the device performance parameters for solar cells fabricated with different concentrations of MPTMS. (a) PCE. (b) V_{oc} . (c) J_{sc} . (d) FF.

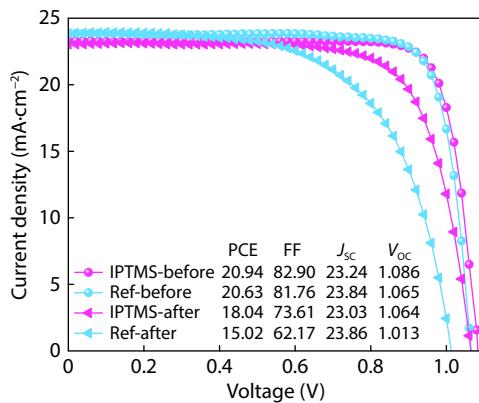


Fig. S4. J - V curve of IPTMS-treated and untreated device at 60%RH condition for 0 and 24 h.

Table 1. EIS parameters of the devices based on the pristine and IPTMS modification.

Parameter	R_{tr} (Ω)	R_{rec} (Ω)	C_1 (F)	C_2 (F)
Control	1.021×10^6	2.092×10^6	3.881×10^{-9}	6.202×10^{-8}
Target	6.413×10^5	8.233×10^6	7.227×10^{-9}	1.529×10^{-7}